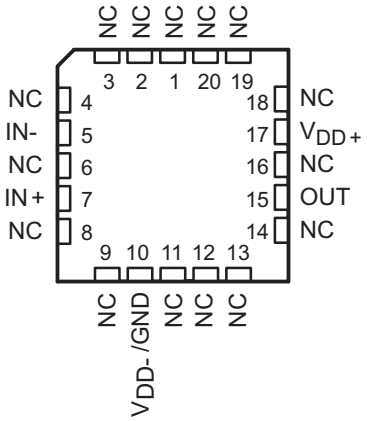
CLASS V, ADVANCED LinCMOS™ LOW NOISE PRECISION OPERATIONAL AMPLIFIER

Check for Samples: TLC2201-SP

FEATURES

- **QML-V Qualifed SMD 5962-9088203V2A**
- **Low Input Offset Voltage: 400 µV Max**
- **Excellent Offset Voltage Stability With Temperature: 0.5 µV/°C Typ**
- **Rail-to-Rail Output Swing**
- **Low Input Bias Current: 1 pA Typ at T_A = 25°C**
- **Common-Mode Input Voltage Range Includes the Negative Rail**
- **Fully Specified For Both Single-Supply and Split-Supply Operation**

FK PACKAGE
(TOP VIEW)



NC - No internal connection

DESCRIPTION

The TLC2201 is a precision, low-noise operational amplifier using Texas Instruments Advanced LinCMOS™ process. This device combines the noise performance of the lowest-noise JFET amplifiers with the dc precision available previously only in bipolar amplifiers. The Advanced LinCMOS™ process uses silicon-gate technology to obtain input offset voltage stability with temperature and time that far exceeds that obtainable using metal-gate technology. In addition, this technology makes possible input impedance levels that meet or exceed levels offered by top-gate JFET and expensive dielectric-isolated devices.

The combination of excellent DC and noise performance with a common-mode input voltage range that includes the negative rail makes these devices an ideal choice for high-impedance, low-level signal-conditioning applications in either single-supply or split-supply configurations.

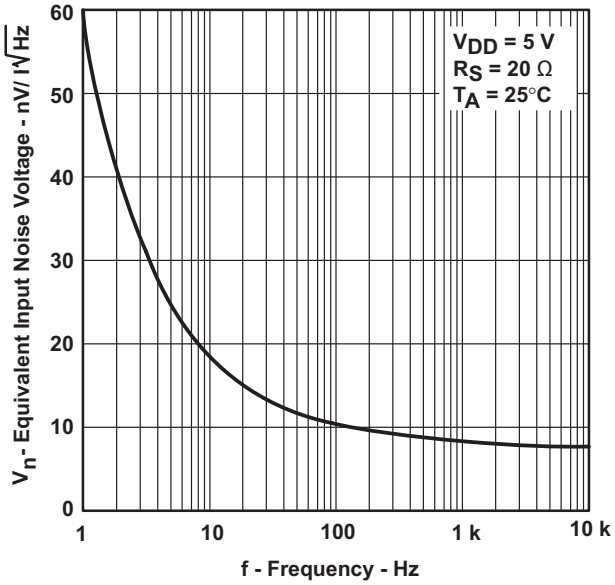
The device inputs and outputs are designed to withstand −100-mA surge currents without sustaining latch-up. In addition, internal ESD-protection circuits prevent functional failures at voltages up to 2000 V as tested under MIL-PRF-38535, Method 3015.2; however, care should be exercised in handling these devices as exposure to ESD may result in degradation of the parametric performance.

The TLC2201 is characterized for operation over the full military temperature range of −55°C to 125°C.

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

TYPICAL EQUIVALENT INPUT NOISE VOLTAGE vs FREQUENCY



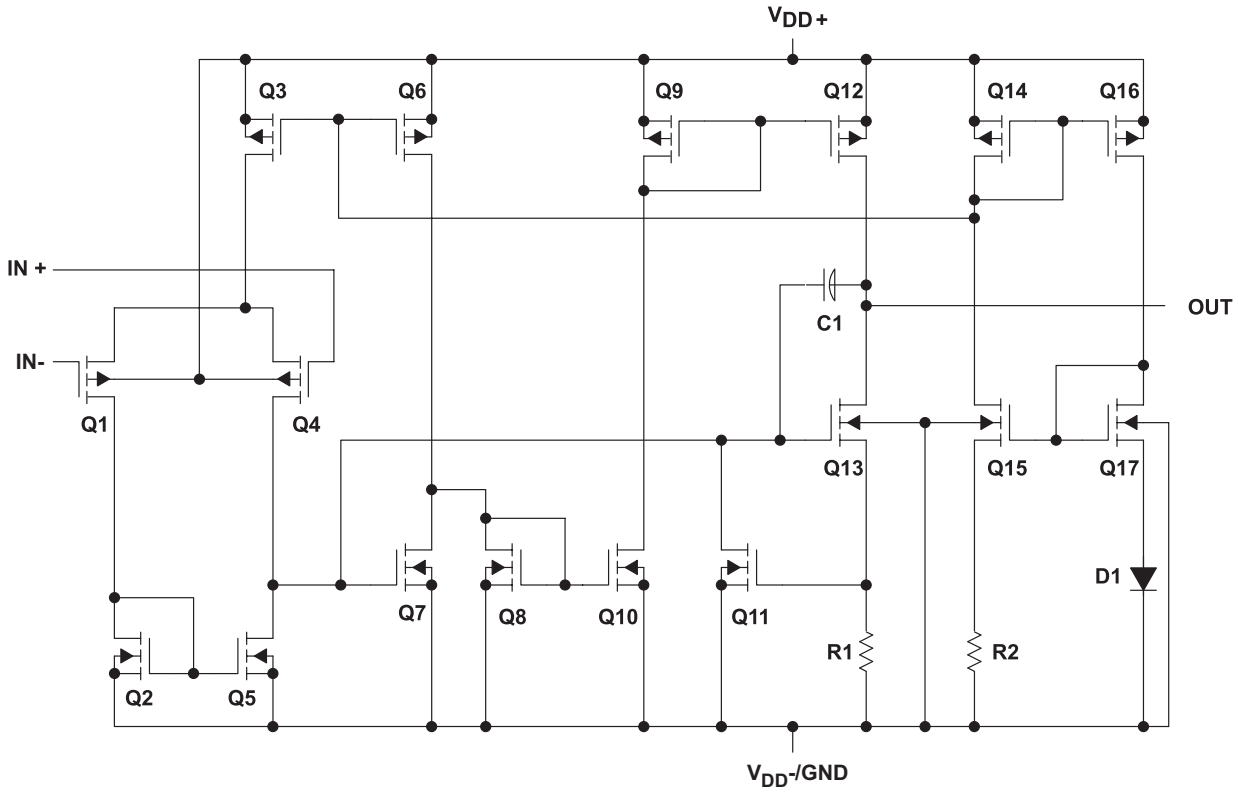
ORDERING INFORMATION(1)

TEMPERATURE	PACKAGE(2)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–55°C to 125°C T_{case}	20-pin FK	5962-9088203V2A	5962-9088203V2A TLC2201AMFKBQMLV

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

EQUIVALENT SCHEMATIC



ACTUAL DEVICE COMPONENT COUNT	
COMPONENT	**TLC2201**
Transistors	17
Resistors	2
Diodes	1
Capacitors	1

ABSOLUTE MAXIMUM RATINGS(1)

Over operating free-air temperature range (unless otherwise noted).

		VALUE	UNIT
V_{DD}	Supply voltage(2), V_{DD-} to V_{DD+}	-8 to 8	V
V_{ID}	Differential input voltage(3)	±16	V
V_I	Input voltage (any input)	±8	V
I_I	Input current (each input)	±5	mA
I_O	Output current (each output)	±50	mA
	Duration of short-circuit current at (or below) 25°C(4)	Unlimited	
	Continuous total power dissipation	See Dissipation Ratings Table	
T_C	Operating case temperature	–55 to 125	°C
T_{stg}	Storage temperature	–65 to 150	°C
	Case temperature for 60 seconds	260	°C

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltage values except differential voltages are with respect to the midpoint between V_{DD+} and V_{DD-}.
(3) Differential voltages are at IN+ with respect to IN−.
(4) The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating in not exceeded.

THERMAL RESISTANCE FOR FK PACKAGE(1)(2)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-case thermal resistance	MIL-STD-883 test method 1012			16	°C/W

(1) Maximum power dissipation is a function of T_J (max), θ_{JC} and T_C. The maximum allowable power dissipation at any allowable case temperature is PD = (T_J (max) - T_C)/θ_{JC}. Operating at the absolute maximum T_J of 150°C can affect reliability.
(2) The package thermal impedance is calculated in accordance with MIL-STD-883.

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
$V_{DD\pm}$	Supply voltage	±2.3	±8	V
V_{IC}	Common-mode input voltage	V_{DD-}	V_{DD+}-2.3	V
T_C	Operating case temperature	–55	125	°C

ELECTRICAL CHARACTERISTICS

over operating free-air temperature range, V_{DD} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T_A (1)	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	V_{IC} = 0, R_S = 50 Ω	25°C		80	200	μV
			Full range			400	
α_{VIO}	Temperature coefficient of input offset voltage		Full range		0.5		μV/°C
	Input offset voltage long-term drift (2)		25°C		0.001		μV/mo
I_{IO}	Input offset current		25°C		0.5		pA
			Full range			500	
I_{IB}	Input bias current		25°C		1		pA
			Full range			500	
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω	Full range	0 to 2.7			V
V_{OH}	Maximum high-level output voltage	R_L = 10 kΩ	25°C	4.7	4.8		V
			Full range	4.7			
V_{OL}	Maximum low-level output voltage	I_O = 0	25°C		0	50	mV
			Full range			50	
A_{VD}	Large-signal differential voltage amplification	V_O = 1 V to 4 V, R_L = 500 kΩ	25°C	150	315		V/mV
			Full range	75			
		V_O = 1 V to 4 V, R_L = 10 kΩ	25°C	25	55		
			Full range	10			
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω	25°C	90	110		dB
			Full range	85			
k_{SVR}	Supply voltage rejection ratio ($\Delta V_{DD\pm}/\Delta V_{IO}$)	V_{DD} = 4.6 V to 16 V	25°C	90	110		dB
			Full range	85			
I_{DD}	Supply current	V_O = 2.5 V, No load	25°C		1.1	1.5	mA
			Full range			1.5	
SR	Slew rate at unity gain	V_O = 0.5 V to 2.5 V, R_L = 10 kΩ C_L = 100 pF	25°C	1.8	2.5		V/μs
			Full range	1.1			
V_n	Equivalent input noise voltage	f = 10 Hz	25°C		18		nV/√Hz
		f = 1 kHz	25°C		8		
$V_{n(pp)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 to 1 Hz	25°C		0.5		μV
		f = 0.1 to 10 Hz	25°C		0.7		
I_n	Equivalent input noise current		25°C		0.6		fA/√Hz
	Gain-bandwidth product	f = 10 kHz, RL = 10 kΩ, CL = 100 pF	25°C		1.8		MHz
φ_m	Phase margin at unity gain	R_L = 10 kΩ, C_L = 100 pF	25°C		45°		

(1) Full range is −55°C to 125°C.
(2) Typical values are based on the input offset voltage shift observable through 168 hours of operating life test at T_A = 150°C extrapolated to T_A = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

ELECTRICAL CHARACTERISTICS

over operating free-air temperature range, V_{DD} = ±5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T_A (1)	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	V_{IC} = 0, R_S = 50 Ω	25°C		80	200	µV
			Full range			400	
α_{VIO}	Temperature coefficient of input offset voltage		Full range		0.5		µV/°C
	Input offset voltage long-term drift (2)		25°C		0.001		µV/mo
I_{IO}	Input offset current		25°C		0.5		pA
			Full range			500	
I_{IB}	Input bias current		25°C		1		pA
			Full range			500	
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω	Full range	-5 to 2.7			V
V_{OM+}	Maximum positive peak output voltage swing	R_L = 10 kΩ	25°C	4.7	4.8		V
			Full range	4.7			
V_{OM-}	Maximum negative peak output voltage swing		25°C	-4.7	-4.9		V
			Full range	-4.7			
A_{VD}	Large-signal differential voltage amplification	V_O = ±4 V, R_L = 500 kΩ	25°C	400	560		V/mV
			Full range	200			
		V_O = ±4 V, R_L = 10 kΩ	25°C	90	100		
			Full range	45			
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω	25°C	90	115		dB
			Full range	85			
k_{SVR}	Supply voltage rejection ratio ($\Delta V_{DD\pm}/\Delta V_{IO}$)	V_{DD} = ±2.3 V to ±8 V	25°C	90	110		dB
			Full range	85			
I_{DD}	Supply current	V_O = 0 V, No load	25°C		1.1	1.5	mA
			Full range			1.5	
SR	Slew rate at unity gain	V_O = ±2.3 V, R_L = 10 kΩ C_L = 100 pF	25°C	2	2.7		V/µs
			Full range	1.3			
V_n	Equivalent input noise voltage	f = 10 Hz	25°C		18		nV/√Hz
		f = 1 kHz	25°C		8		
$V_{n(pp)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 to 1 Hz	25°C		0.5		µV
		f = 0.1 to 10 Hz	25°C		0.7		
I_n	Equivalent input noise current		25°C		0.6		fA/√Hz
	Gain-bandwidth product	f = 10 kHz, RL = 10 kΩ, CL = 100 pF	25°C		1.9		MHz
φ_m	Phase margin at unity gain	R_L = 10 kΩ, C_L = 100 pF	25°C		48°		

(1) Full range is −55°C to 125°C.
(2) Typical values are based on the input offset voltage shift observable through 168 hours of operating life test at T_A = 150°C extrapolated to T_A = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

PARAMETER MEASUREMENT INFORMATION

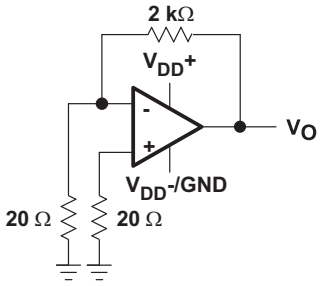
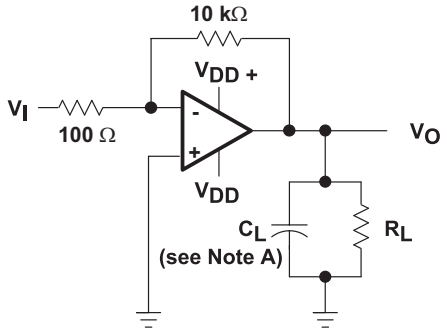
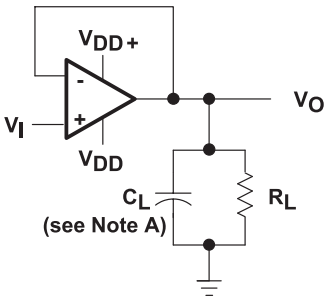


Figure 1. Noise-Voltage Test Circuit



NOTE A: C_L includes fixture capacitance.

Figure 2. Phase-Margin Test Circuit



NOTE A: C_L includes fixture capacitance.

Figure 3. Slew-Rate Test Circuit

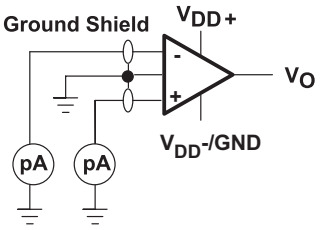


Figure 4. Input-Bias and Offset-Current Test Circuit

TYPICAL VALUES

Typical values presented in this data sheet represent the median (50% point) of device parametric performance.

INPUT BIAS AND OFFSET CURRENT

At the picoamp bias current level of the TLC2201 accurate measurement of the bias current becomes difficult. Not only does this measurement require a picoammeter, but test socket leakages can easily exceed the actual device bias currents. To measure these small currents, Texas Instruments uses a two-step process. The socket leakage is measured using picoammeters with bias voltages applied but with no device in the socket. The device is then inserted in the socket, and a second test measuring both the socket leakage and the device input bias current is performed. The two measurements are then subtracted algebraically to determine the bias current of the device.

NOISE

Texas Instruments offers automated production noise testing to meet individual application requirements. Noise voltage at f = 10 Hz and f = 1 kHz is sample tested on every TLC2201. For other noise requirements, please contact the factory.

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	Distribution	Figure 5
I_{IB}	Input bias current	vs Common-mode input voltage	Figure 6
		vs Free-air temperature	Figure 7
V_{OM}	Maximum peak output voltage	vs Output curre	Figure 8
		vs Free-air temperature	Figure 9
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	Figure 10
V_{OH}	High-level output voltage	vs Frequency	Figure 11
		vs High-level output current	Figure 12
		vs Free-air temperature	Figure 13
V_{OL}	Low-level output voltage	vs Low-level output current	Figure 14
		vs Free-air temperature	Figure 15
A_{VD}	Large-signal differential voltage amplification	vs Frequency	Figure 16
		vs Free-air temperature	Figure 17
I_{OS}	Short-circuit output current	vs Supply voltage	Figure 18
		vs Free-air temperature	Figure 19
CMRR	Common-mode rejection ratio	vs Frequency	Figure 20
I_{DD}	Supply current	vs Supply voltage	Figure 21
		vs Free-air temperature	Figure 22
	Pulse response	Small signal	Figure 23
			Figure 24
		Large signal	Figure 25
			Figure 26
SR	Slew rate	vs Supply voltage	Figure 27
		vs Free-air temperature	Figure 28
	Noise voltage (referred to input)	0.1 Hz to 1 Hz	Figure 29
		0.1 Hz to 10 Hz	Figure 30
	Gain-bandwidth product	vs Supply voltage	Figure 31
		vs Free-air temperature	Figure 32
φ_m	Phase margin	vs Supply voltage	Figure 33
		vs Free-air temperature	Figure 34
	Phase shift	vs Frequency	Figure 16

TYPICAL CHARACTERISTICS

INPUT OFFSET VOLTAGE DISTRIBUTION

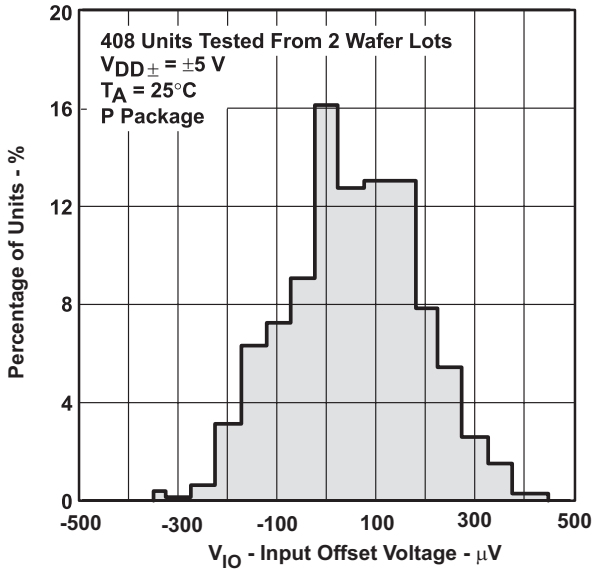


Figure 5.

INPUT BIAS CURRENT
vs
COMMON-MODE INPUT VOLTAGE

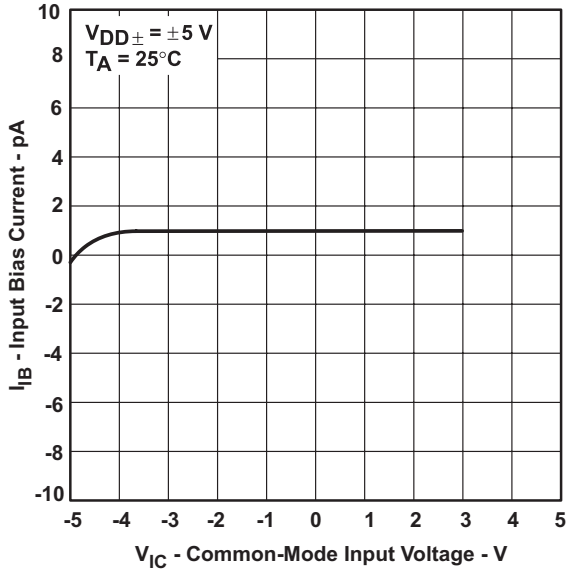


Figure 6.

INPUT BIAS CURRENT(1)
vs
FREE-AIR TEMPERATURE

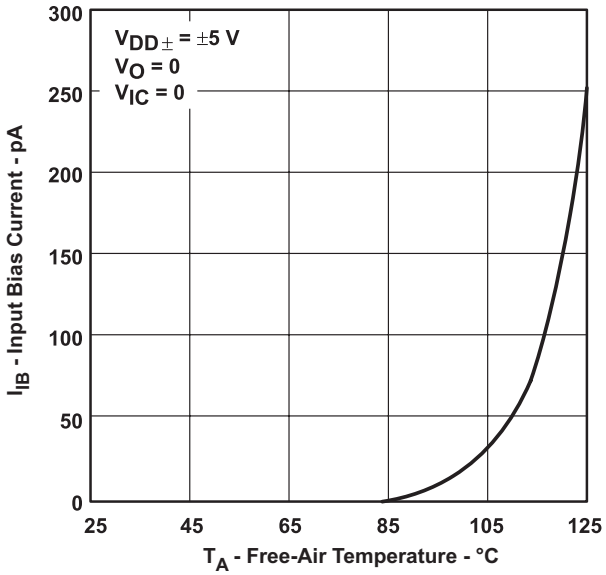


Figure 7.

MAXIMUM PEAK OUTPUT VOLTAGE
vs
OUTPUT CURRENT

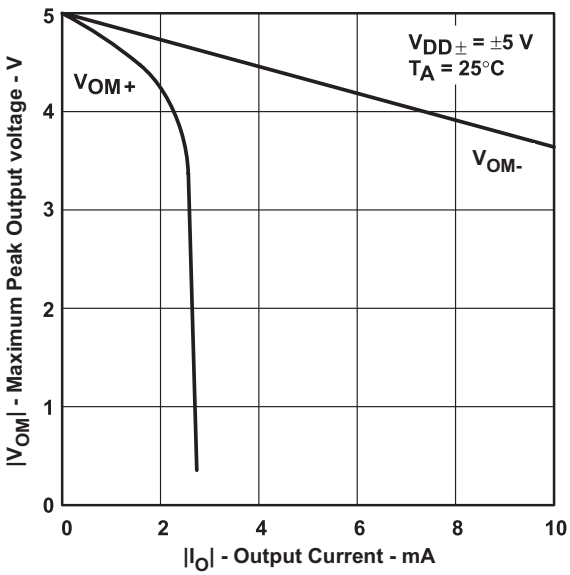


Figure 8.

(1) Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS (continued)

MAXIMUM PEAK OUTPUT VOLTAGE[2] vs FREE-AIR TEMPERATURE

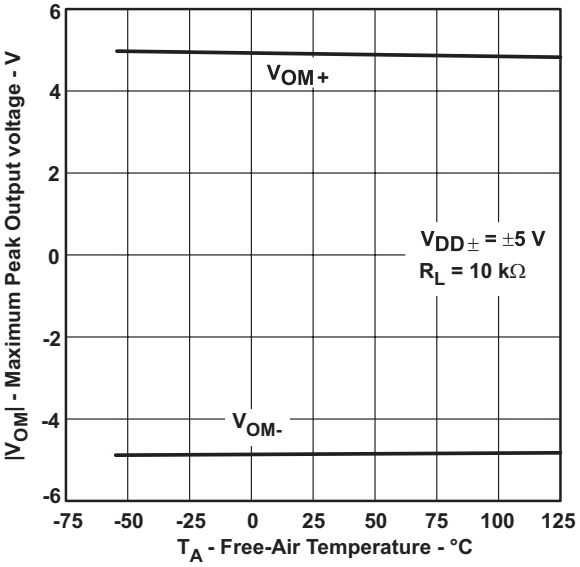


Figure 9.

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE vs FREQUENCY

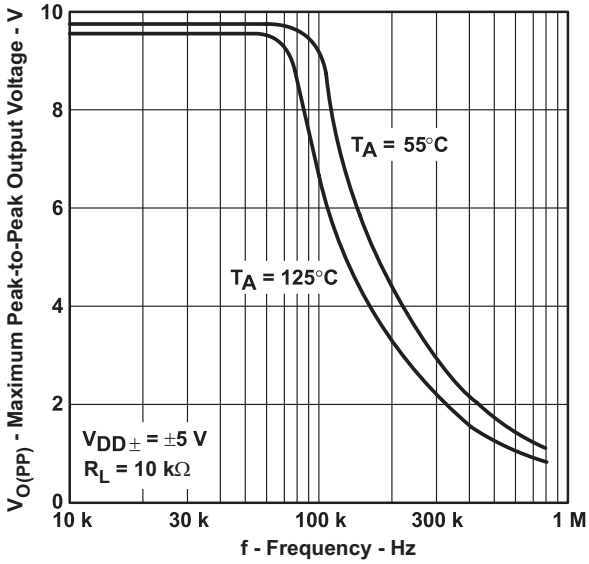


Figure 10.

HIGH-LEVEL OUTPUT VOLTAGE vs FREQUENCY

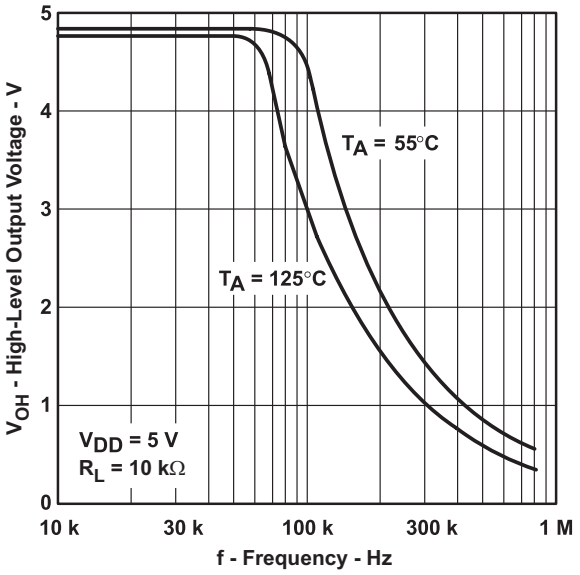


Figure 11.

HIGH-LEVEL OUTPUT VOLTAGE vs HIGH-LEVEL OUTPUT CURRENT

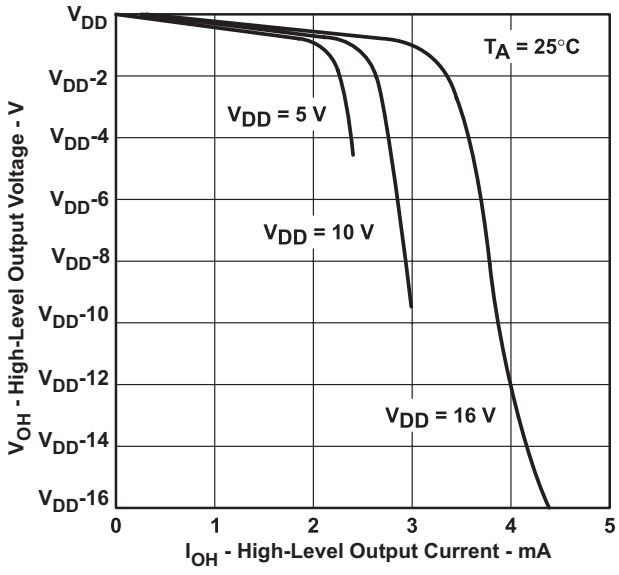


Figure 12.

(2) Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS (continued)

HIGH-LEVEL OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE

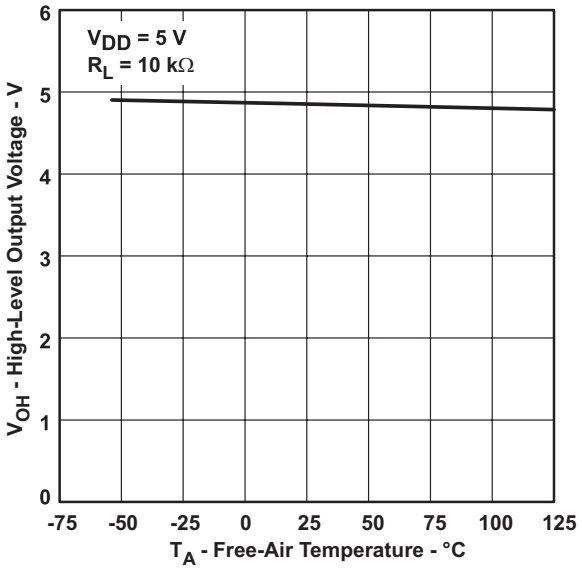


Figure 13.

LOW-LEVEL OUTPUT VOLTAGE
vs
LOW-LEVEL OUTPUT CURRENT

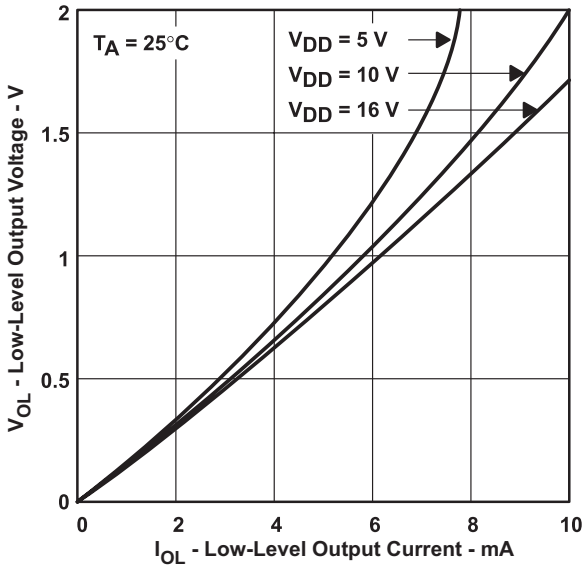


Figure 14.

LOW-LEVEL OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE

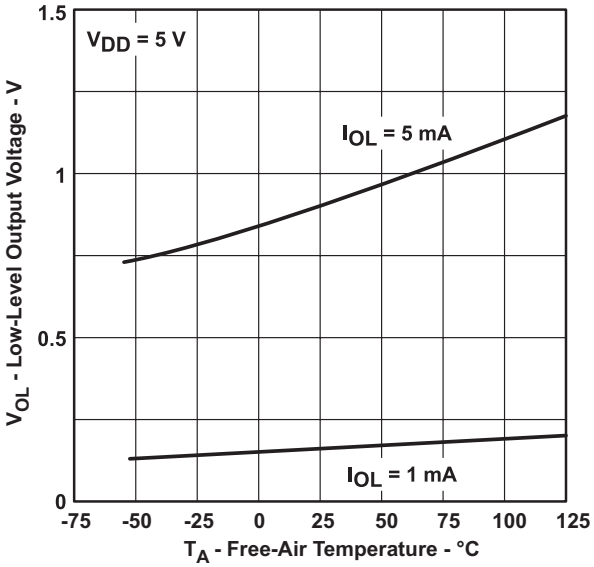


Figure 15.

LARGE-SIGNAL DIFFERENTIAL VOLTAGE
AMPLIFICATION AND PHASE SHIFT
vs
FREQUENCY

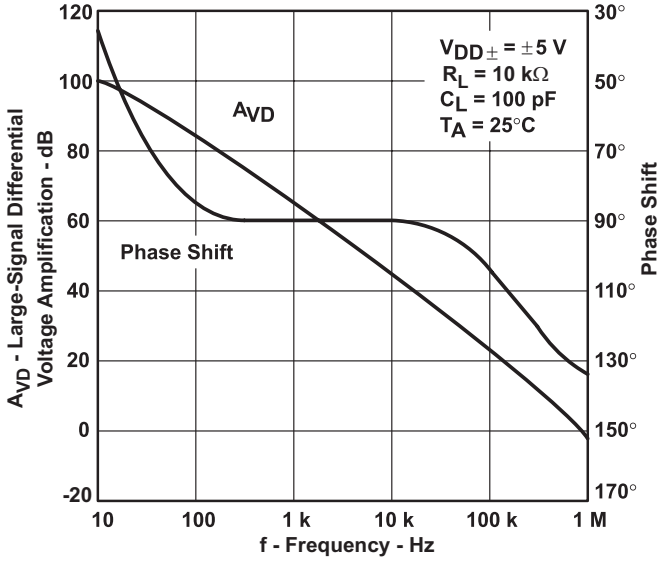


Figure 16.

TYPICAL CHARACTERISTICS (continued)

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION vs FREE-AIR TEMPERATURE

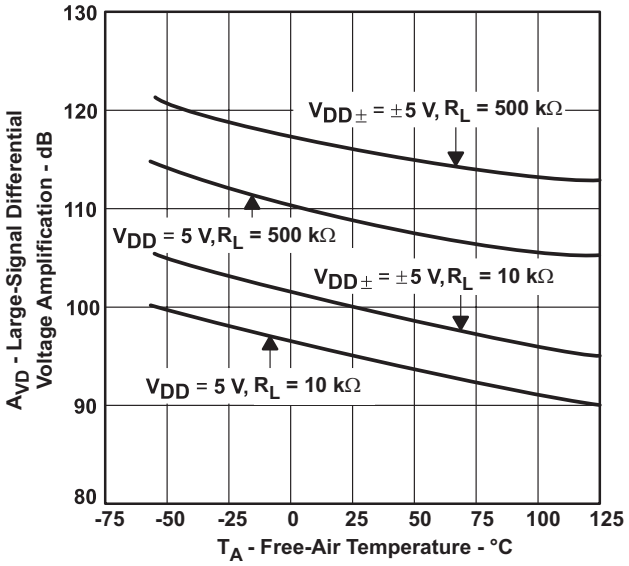


Figure 17.

SHORT-CIRCUIT OUTPUT CURRENT vs SUPPLY VOLTAGE

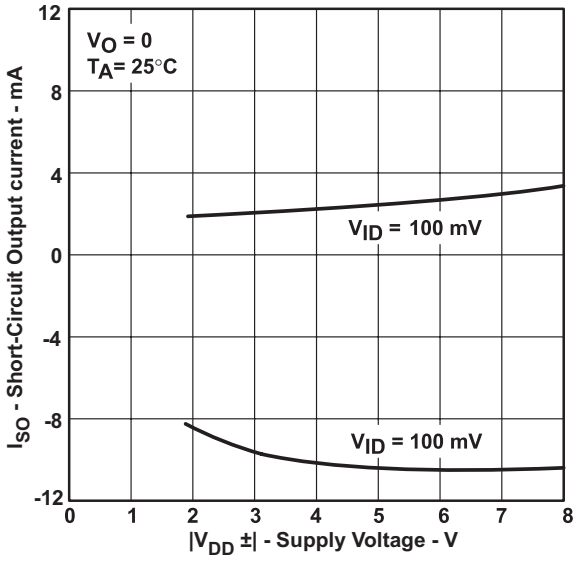


Figure 18.

SHORT-CIRCUIT OUTPUT CURRENT vs FREE-AIR TEMPERATURE

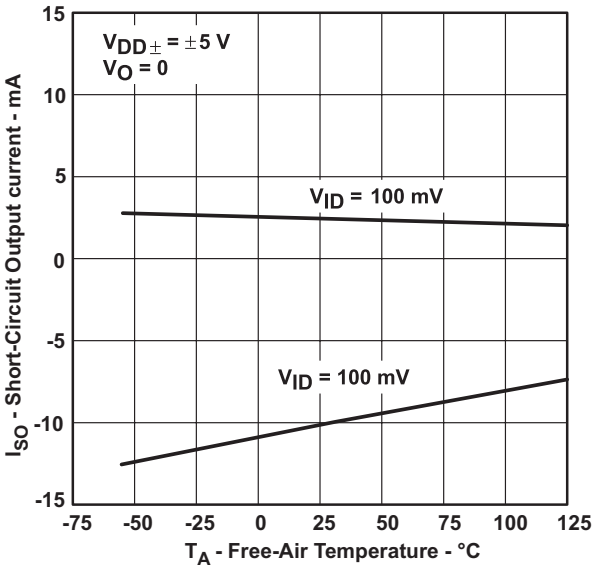


Figure 19.

COMMON-MODE REJECTION RATIO vs FREQUENCY

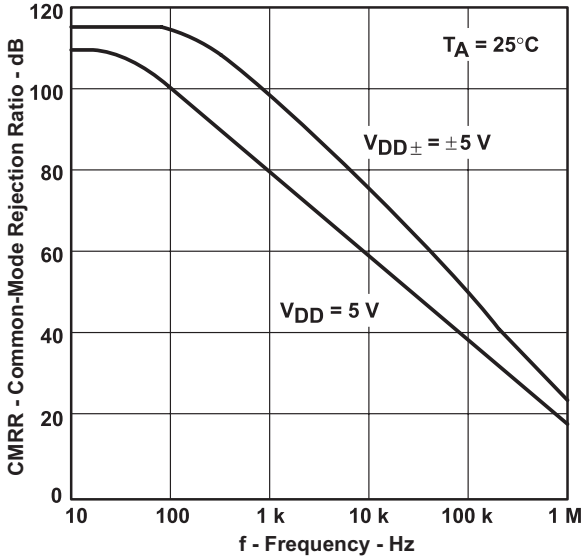


Figure 20.

TYPICAL CHARACTERISTICS (continued)

SUPPLY CURRENT vs SUPPLY VOLTAGE

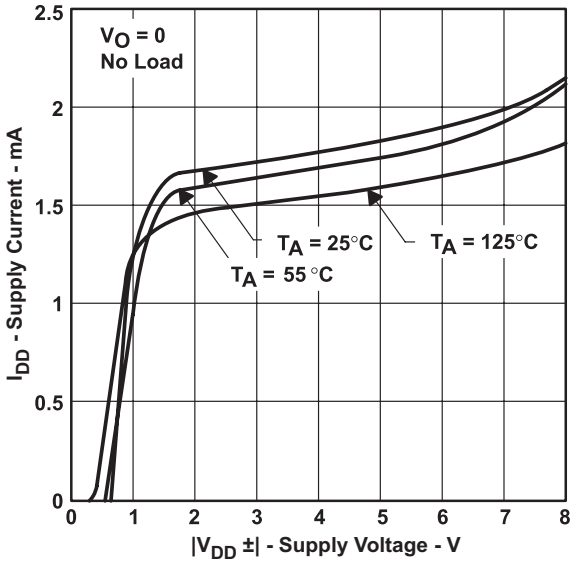


Figure 21.

SUPPLY CURRENT vs FREE-AIR TEMPERATURE

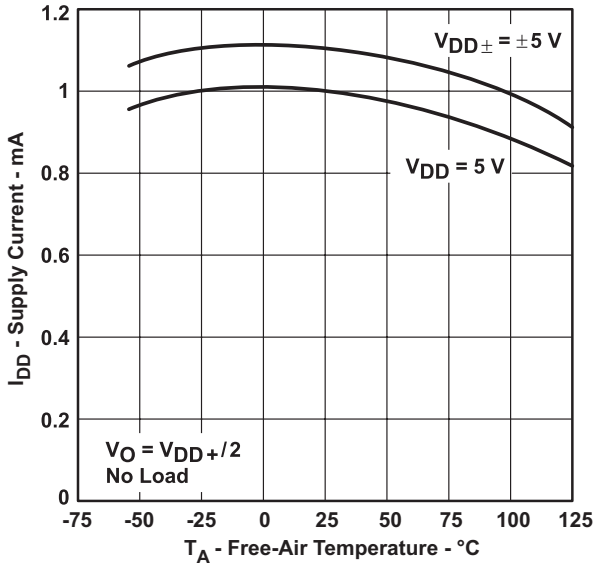


Figure 22.

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE

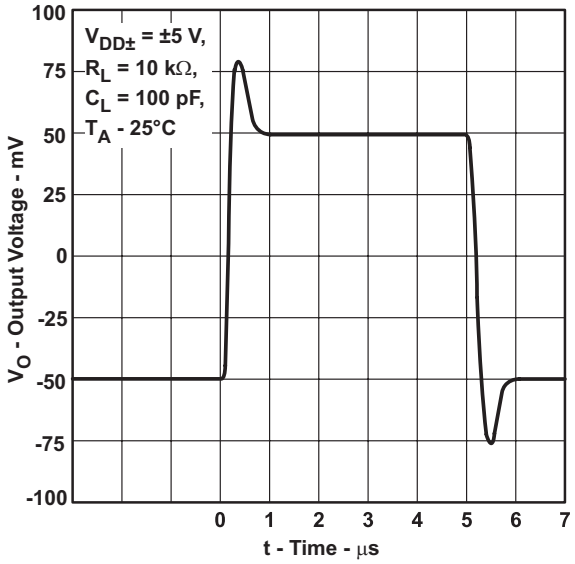


Figure 23.

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE

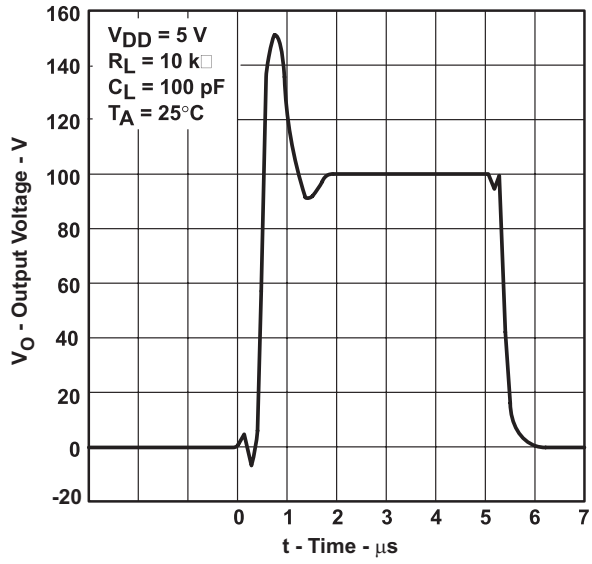


Figure 24.

TYPICAL CHARACTERISTICS (continued)

VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

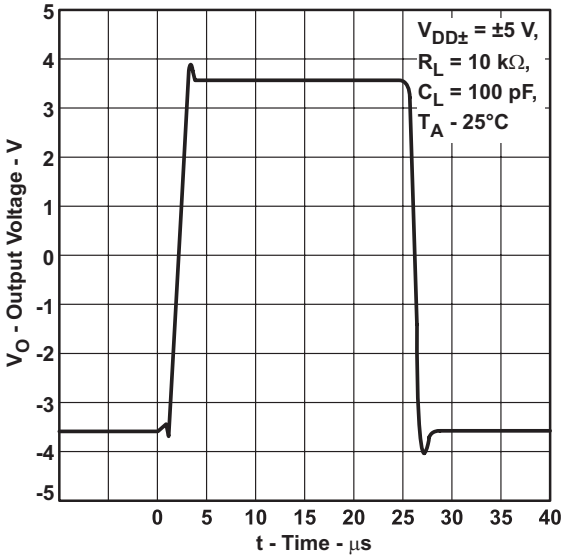


Figure 25.

VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

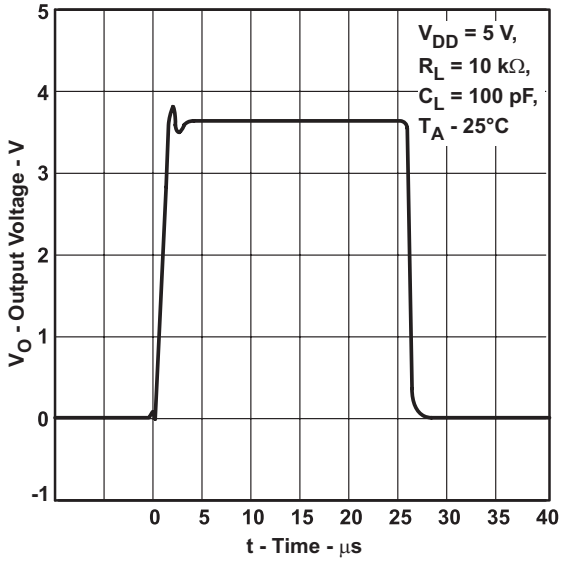


Figure 26.

SLEW RATE vs SUPPLY VOLTAGE

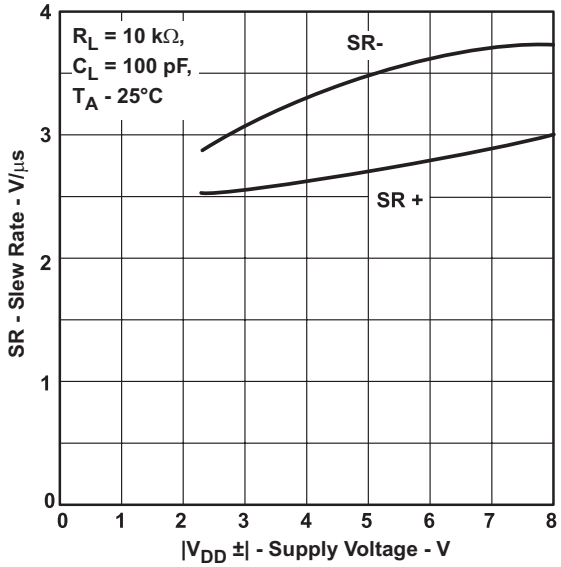


Figure 27.

SLEW RATE vs FREE-AIR TEMPERATURE

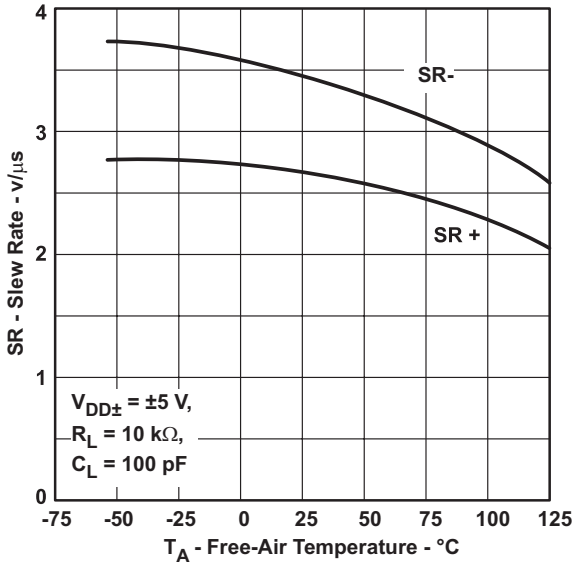


Figure 28.

TYPICAL CHARACTERISTICS (continued)

NOISE VOLTAGE
(REFERRED TO INPUT)
OVER A 10-SECOND INTERVAL

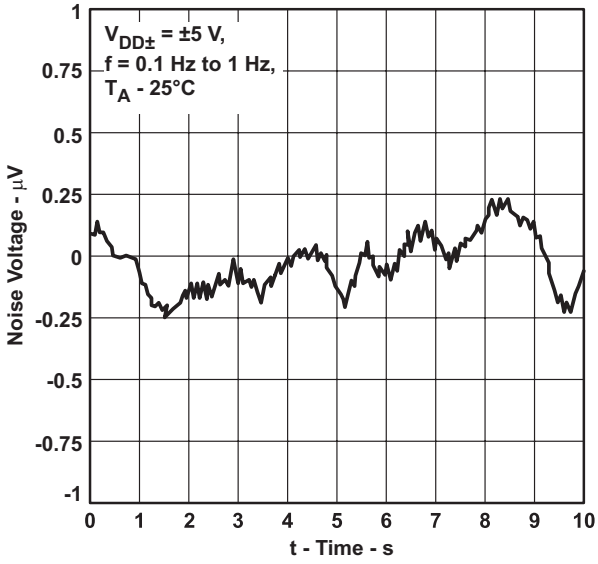


Figure 29.

NOISE VOLTAGE
(REFERRED TO INPUT)
OVER A 10-SECOND INTERVAL

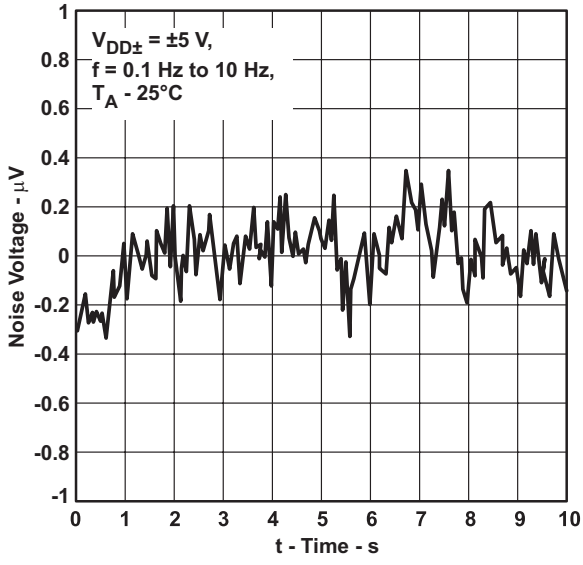


Figure 30.

GAIN-BANDWIDTH PRODUCT
vs
SUPPLY VOLTAGE

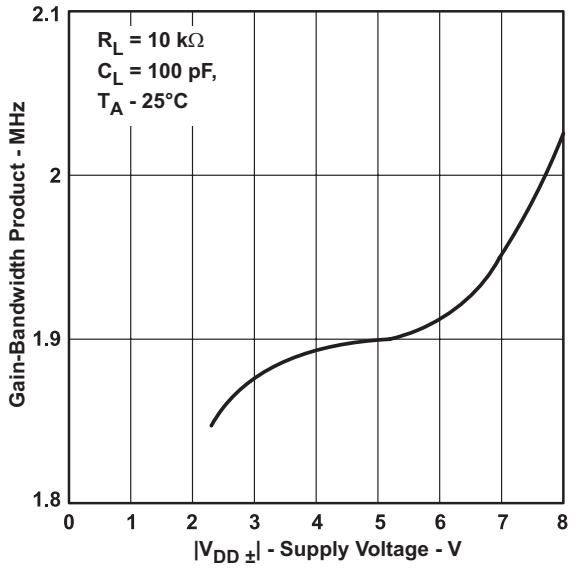


Figure 31.

GAIN-BANDWIDTH PRODUCT
vs
FREE-AIR TEMPERATURE

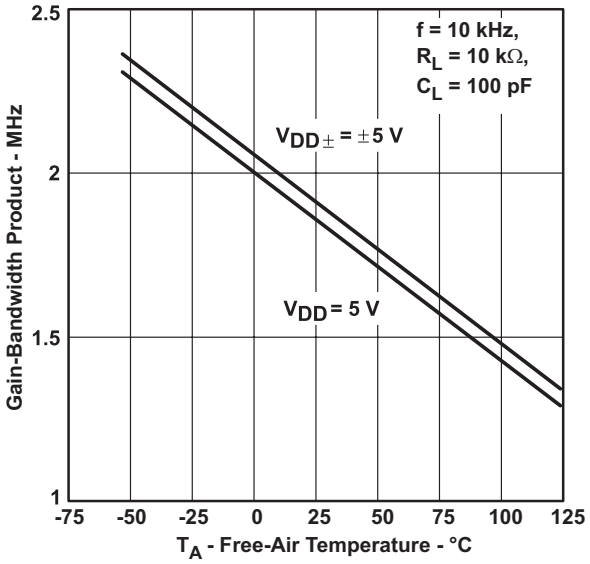


Figure 32.

TYPICAL CHARACTERISTICS (continued)

PHASE MARGIN vs SUPPLY VOLTAGE

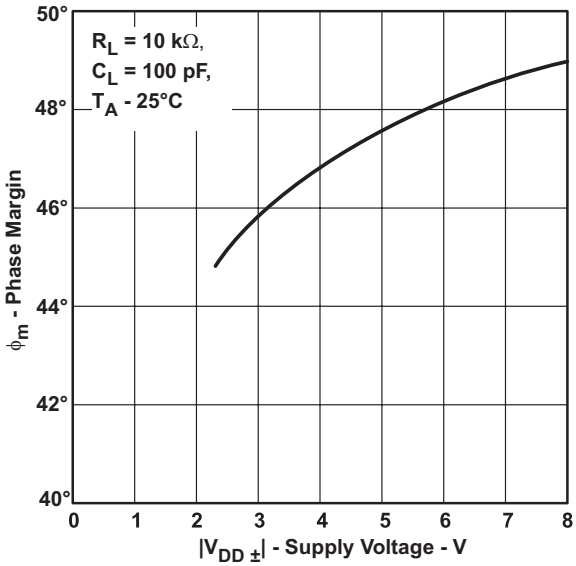


Figure 33.

PHASE MARGIN vs FREE-AIR TEMPERATURE

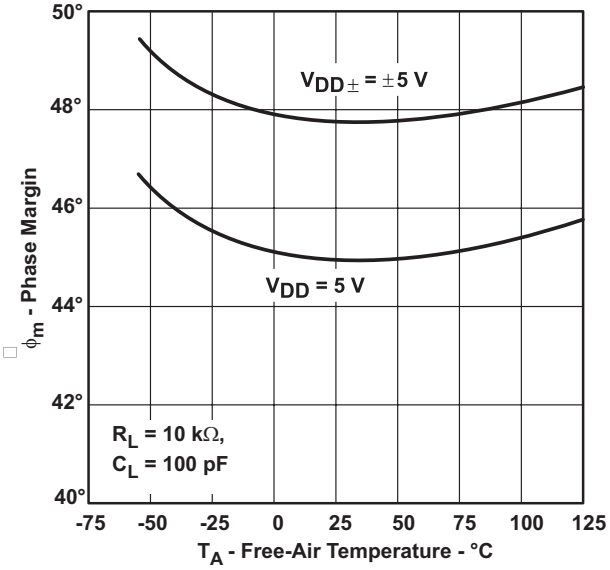


Figure 34.

APPLICATION INFORMATION

LATCH-UP AVOIDANCE

Because CMOS devices are susceptible to latch-up due to their inherent parasitic thyristors, the TLC2201 inputs and outputs are designed to withstand −100-mA surge currents without sustaining latch-up; however, techniques reducing the chance of latch-up should be used whenever possible. Internal protection diodes should not be forward biased in normal operation. Applied input and output voltages should not exceed the supply voltage by more than 300 mV. Care should be exercised when using capacitive coupling on pulse generators. Supply transients should be shunted by the use of decoupling capacitors (0.1 µF typical) located across the supply rails as close to the device as possible.

ELECTROSTATIC DISCHARGE PROTECTION

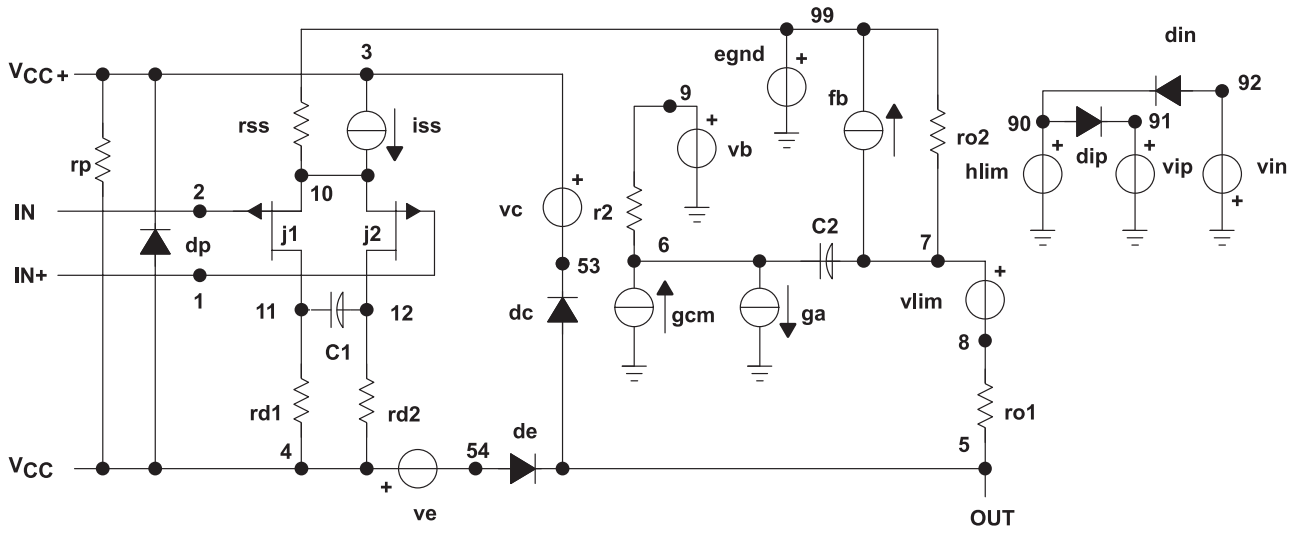
These devices use internal ESD-protection circuits that prevent functional failures at voltages at or below 2000 V. Care should be exercised in handling these devices as exposure to ESD may result in degradation of the device parametric performance.

MACROMODEL INFORMATION

Macromodel information provided was derived using Microsim Parts™, the model generation software used with Microsim PSpice™. The Boyle macromodel(3) and subcircuit in Figure 35 were generated using the TLC2201 typical electrical and operating characteristics at 25°C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

(3) G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, “Macromodeling of Integrated Circuit Operational Amplifiers”, IEEE Journal of Solid-State Circuits, SC-9, 353 (1974).




```
.subckt TLC220x  1 2 3 4 5
*
   c1     11   12  8.51E12
   c2     6    7    50.00E12
   cpsr  85   86  79.6E9
   dcm+  81   82  dx
   dcm  83   81  dx
   dc     5    53  dx
   de     54   5    dx
   dlp   90   91  dx
   dln   92   90  dx
   dp     4    3    dx
   ecmr  84   99  (2,99) 1
   egnd  99   0    poly(2) (3,0) (4,0) 0 .5 .5
   epsr  85   0    poly(1) (3,4) 200E6 20E6
   ense  89   2    poly(1) (88,0) 100E6 1
   fb     7    99  poly(6) vb vc ve vlp vln
+  vpsr 0 +     895.9E3 90E3 90E3 90E3 90E3 895E3
   ga     6    0    11 12 314.2E6
   gcm    0    6    10 99 1.295E9
   gpsr  85   86  (85,86) 100E6
   grd1  60   11  (60,11) 3.141E4
   grd2  60   12  (60,12) 3.141E4
   hlim  90   0    vlim 1k
   hcmr  80   1    poly(2) vcm+ vcm 0 1E2 1E2
   irp    3    4    965E6
   iss    3    10  dc 135.0E6
   iio    2    0    .5E12
   i1     88   0    1E21
   j1     11   89  10 jx
   j2     12   80  10 jx
   r2     6    9    100.0E3
   rcm    84   81  1k
   rn1    88   0    1500
   ro1    8    5    188
   ro2    7    99  187
   rss    10   99  1.481E6
   vad    60   4    .3v
   vcm+  82   99  2.2
   vcm  83   99  4.5
   vb     9    0    dc 0
   vc     3    53  dc .9
   ve     54   4    dc .8
   vlim  7    8    dc 0
   vlp    91   0    dc 2.8
   vln    0    92  dc 2.8
   vpsr  0    86  dc 0
.model dx   d(is=800.0E18)
.model jx pjf(is=500.0E15 beta=1.462E3
+ vto=.155 kf=1E17)
.endsx
```

Figure 35. Boyle Macromodel and Subcircuit

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-9088203V2A	Active	Production	LCCC (FK) | 20	55 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9088203V2A TLC2201 AMFKBQMLV
5962-9088203V2A.A	Active	Production	LCCC (FK) | 20	55 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9088203V2A TLC2201 AMFKBQMLV

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

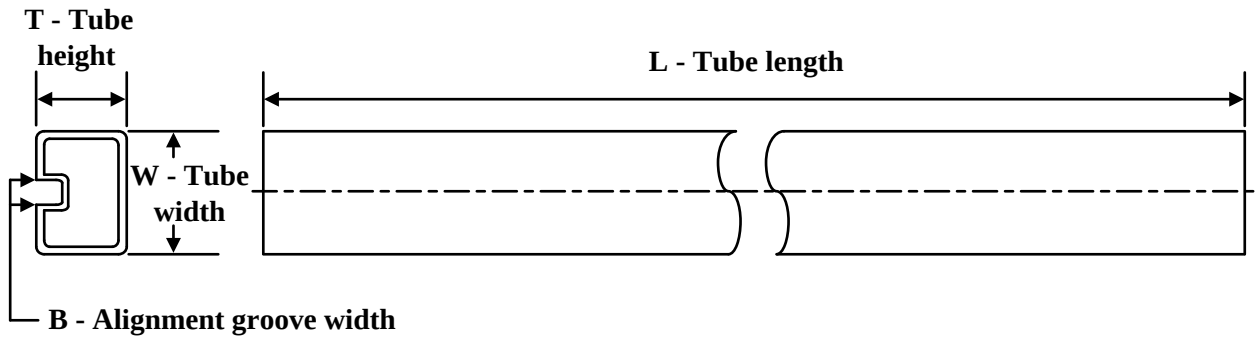
OTHER QUALIFIED VERSIONS OF TLC2201-SP :

- Catalog : TLC2201
- Military : TLC2201M

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9088203V2A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-9088203V2A.A	FK	LCCC	20	55	506.98	12.06	2030	NA

GENERIC PACKAGE VIEW

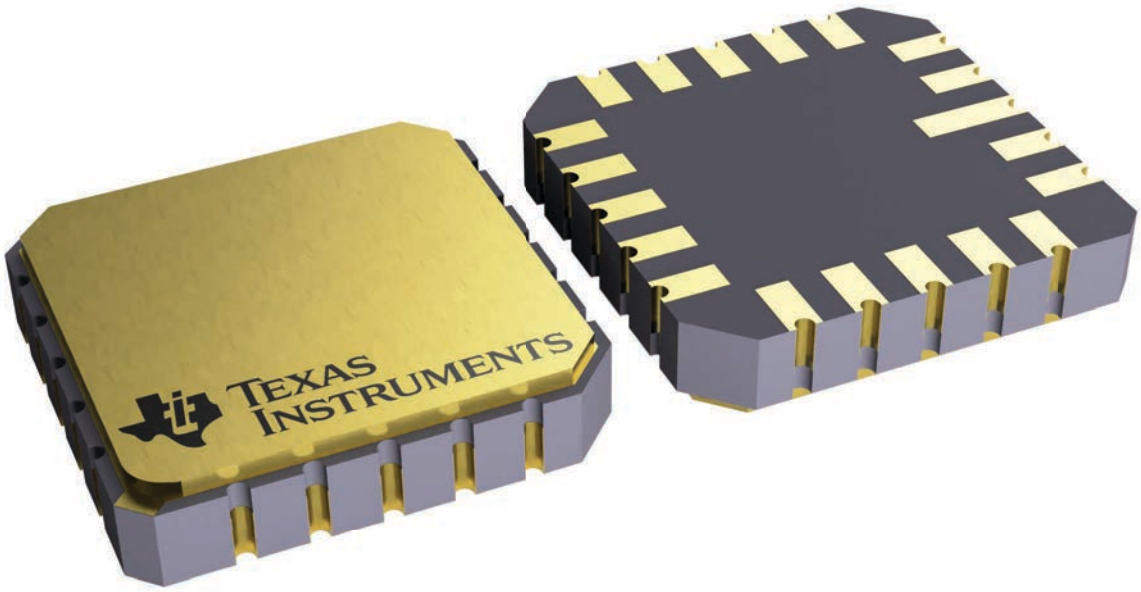
FK 20

LCCC - 2.03 mm max height

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



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Last updated 10/2025